

20 V, P-channel Trench MOSFET 24 January 2014

Product data sheet

#### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1 kV HBM
- Drain-source on-state resistance R<sub>DSon</sub> = 350 mΩ

### 3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

### 4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	-	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	[1]	-	-	-1.2	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 25 °C		-	350	447	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	4 3	G ( The second s
4	D	drain	Transparent top view DFN1010D-3 (SOT1215)	S 017aaa259

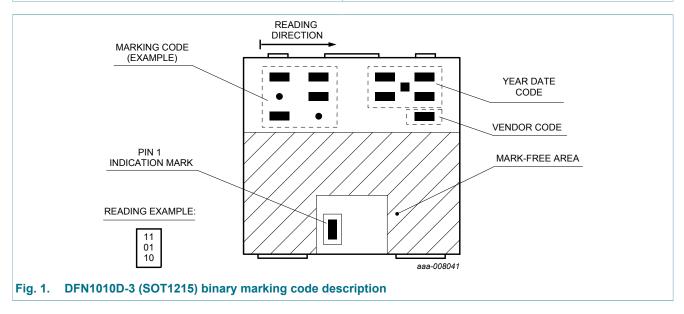
### 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMXB350UPE	DFN1010D-3	DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215				

### 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMXB350UPE	11 10 00



PMXB350UPE

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#### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	[1]	-	-1.2	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 100 °C	[1]	-	-1	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	360	mW
			[1]	-	930	mW
		T <sub>sp</sub> = 25 °C		-	5680	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-0.9	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

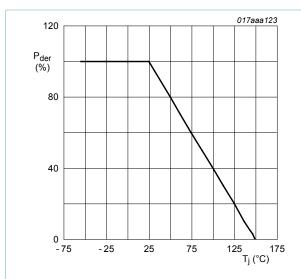
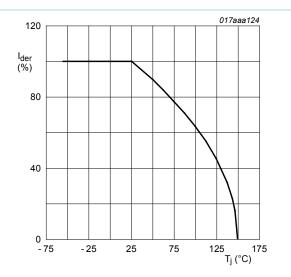


Fig. 2. Normalized total power dissipation as a function of junction temperature

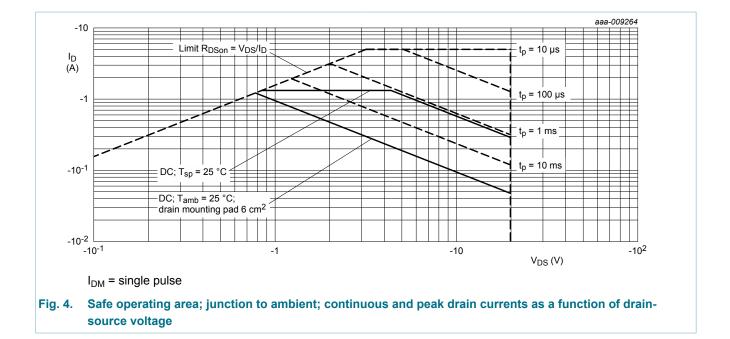
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$





$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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### 9. Thermal characteristics

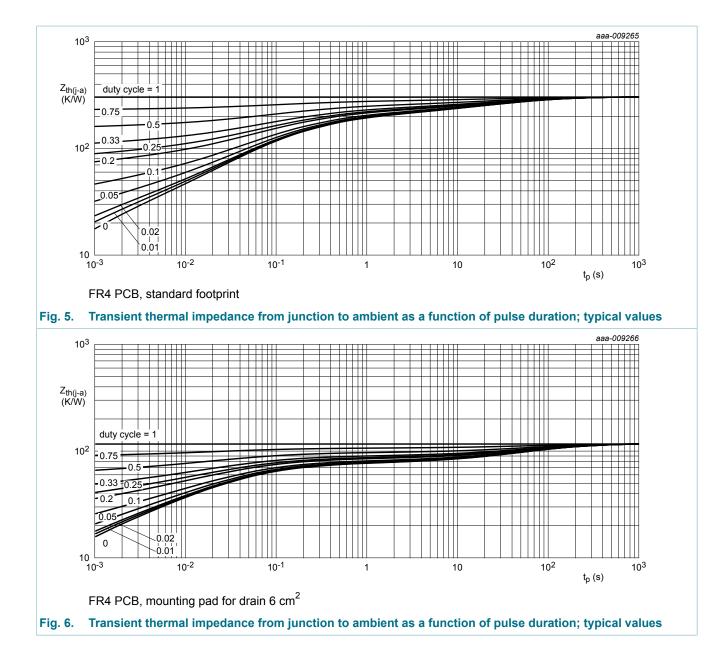
Table 6.         Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
ui(j-a)	thermal resistancein free airfrom junction toambient	in free air	[1]	-	303	348	K/W
			[2]	-	116	134	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	17	22	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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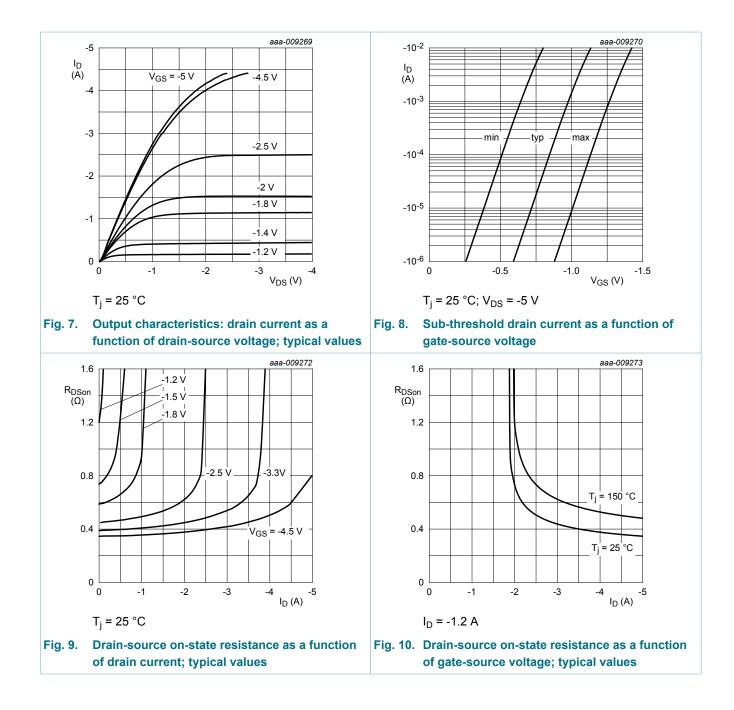
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### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · ·			_	
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.45	-0.7	-0.95	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-10	μA
		V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 25 °C	-	350	447	mΩ
	resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 150 °C	-	508	650	mΩ
		V <sub>GS</sub> = -2.5 V; I <sub>D</sub> = -1 A; T <sub>j</sub> = 25 °C	-	450	645	mΩ
		V <sub>GS</sub> = -1.8 V; I <sub>D</sub> = -0.4 A; T <sub>j</sub> = 25 °C	-	600	940	mΩ
		V <sub>GS</sub> = -1.5 V; I <sub>D</sub> = -10 mA; T <sub>j</sub> = 25 °C	-	760	2000	mΩ
		V <sub>GS</sub> = -1.2 V; I <sub>D</sub> = -1 mA; T <sub>j</sub> = 25 °C	-	1200	-	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = -5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 25 °C	-	5.2	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	0.8	-	Ω
Dynamic ch	aracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; I <sub>D</sub> = -1.2 A; V <sub>GS</sub> = -4.5 V;	-	1.25	2.3	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.27	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.28	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -10 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	116	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	16.5	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	12.2	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; I <sub>D</sub> = -1.2 A; V <sub>GS</sub> = -4.5 V;	-	3	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	9	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	18	-	ns
t <sub>f</sub>	fall time		-	6	-	ns
Source-drai	in diode	· · · · · · · · · · · · · · · · · · ·				
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -0.9 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.8	-1.2	V

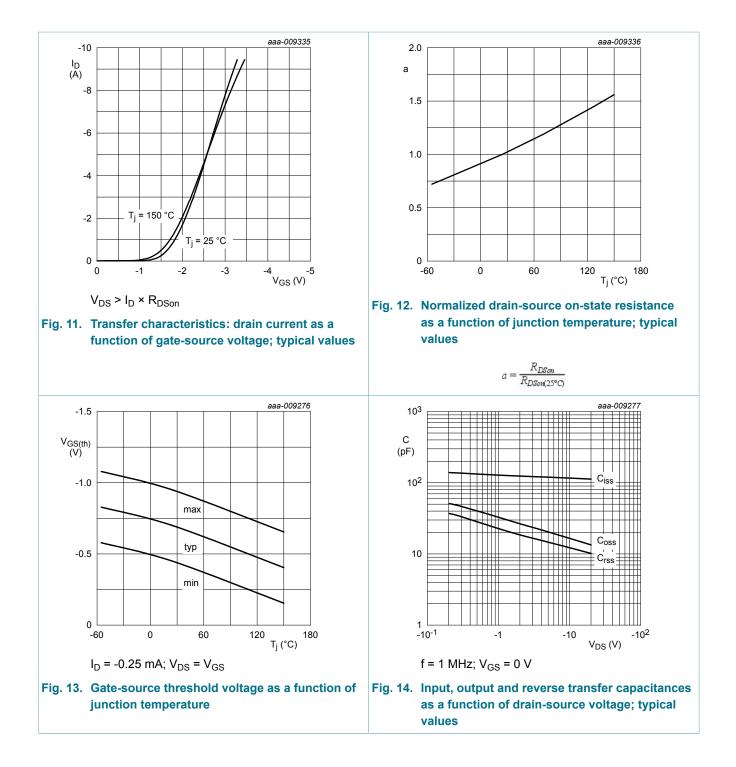
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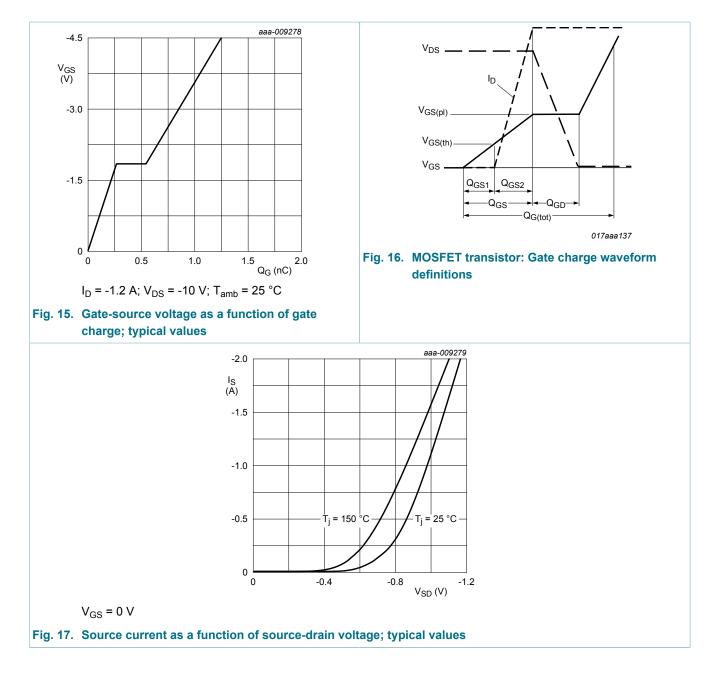
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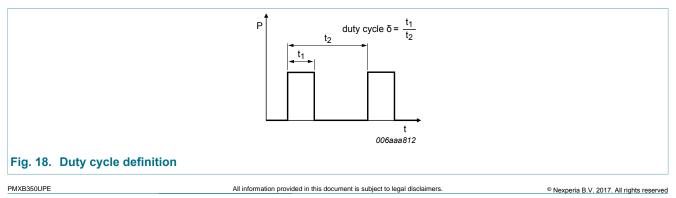
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### PMXB350UPE

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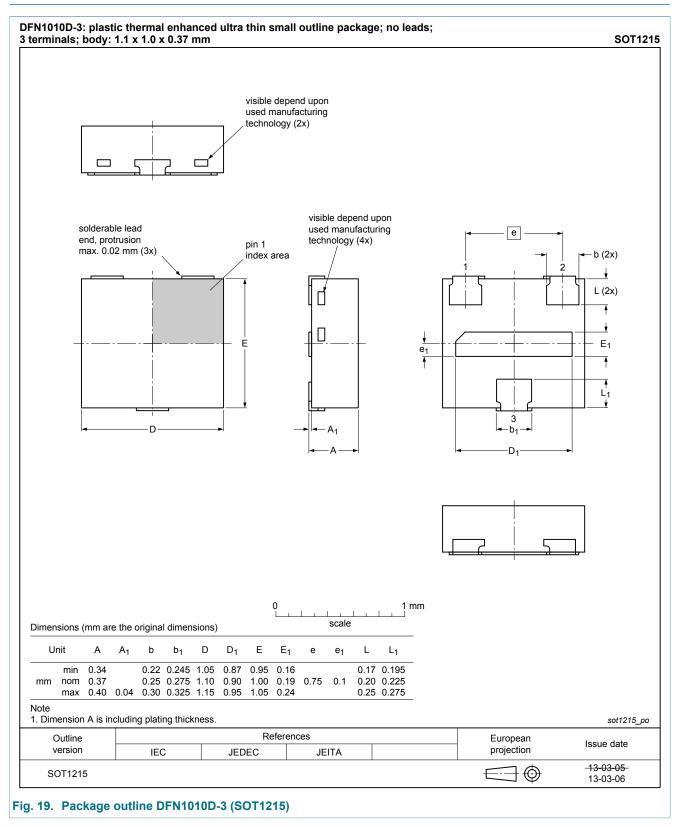


### **11. Test information**



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### 12. Package outline



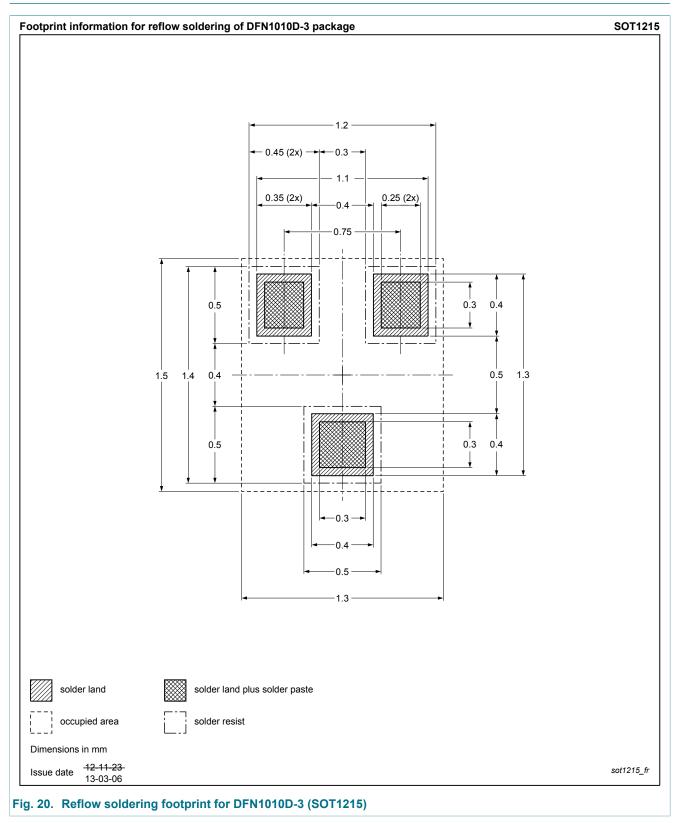
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### **13. Soldering**



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### 14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMXB350UPE v.2	20140124	Product data sheet	-	PMXB350UPE v.1
Modifications:	Editorial update			
PMXB350UPE v.1	20130919	Product data sheet	-	-

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#### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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